



Cite this: *RSC Adv.*, 2017, 7, 6309

In situ synthesis of homogeneous Ce₂S₃/MoS₂ composites and their electrochemical performance for lithium ion batteries

Baoting Hou,^a Xinlu Wang,^a Jinxian Wang,^{*a} Jing Yao,^a Hongbo Zhang,^a Wensheng Yu,^a Guixia Liu,^a Xiangting Dong^a and Limin Wang^b

Homogeneous Ce₂S₃/MoS₂ composite have been fabricated *via* an *in situ* sulfurization method and their structure, morphology and electrochemical properties are researched systematically for the first time. Ce₂S₃/MoS₂ composite present spherical secondary particles of 0.5–1 μm in diameter. The cycling performance and rate property of Ce₂S₃/MoS₂ composite are better than those of Ce₂S₃ and MoS₂ as anode materials for lithium ion batteries. Among them, Ce₂S₃/MoS₂ composite (cationic ratio of Ce : Mo in 4 : 1) have an initial discharge capacity of 225.5 mA h g⁻¹, a coulombic efficiency of 99.1% and a reversible capacity as high as 661.7 mA h g⁻¹, a coulombic efficiency of 99.7% after 500 cycles at a current density of 100 mA g⁻¹ and the highest discharge capacity of 285.6 mA h g⁻¹ at a high current density of 1000 mA g⁻¹, showing the best cycling performance and rate capability among the as-prepared Ce₂S₃/MoS₂ composite. The reason is that the compositing between MoS₂ and Ce₂S₃ can maintain the stability of the structure during the charge/discharge process and the existence of Ce₂S₃ enhances the electrical conductivity of Ce₂S₃/MoS₂ composite and further improves the reversible capacities and rate performance of Ce₂S₃/MoS₂ composite.

Received 18th December 2016
Accepted 12th January 2017

DOI: 10.1039/c6ra28352g

www.rsc.org/advances

1. Introduction

As a development of advanced electronic devices with high energy density, rechargeable lithium-ion batteries (LIBs) have been considered as effective electrochemical energy storage devices due to their advantages of high energy density, long lifespan, no memory effect, high safety and environment-friendliness.^{1–5} Right now, graphite, which is the main anode material for LIBs, cannot reach the increasing demands of the portable electronic device markets due to its low theoretical capacity (372 mA h g⁻¹). MoS₂ has received considerable attention as an anode material for LIBs owing to its high theoretical capacity (669 mA h g⁻¹).^{6–8} Hence, numerous efforts have been made to prepare MoS₂ and its electrochemical performance was studied. For example, Lou *et al.* prepared MoS₂ microspheres consisting of few-layered nanosheets by a polystyrene template-based hydrothermal method, which show enhanced capacity retention and rate capability.⁹ However, low electrical conductivity and volume change during the cycling result in poor cycling and rate performance, which limit their practical application.¹⁰

In recent years, some MoS₂-based composite have been explored as high-performance anode materials for LIBs. Such as MoS₂/carbon black,^{11–13} MoS₂/carbon nanotube^{14–16} (CNT), MoS₂/graphene,^{17–19} MoS₂/carbon fiber cloth,²⁰ MoS₂/amorphous carbon,²¹ MoS₂/SnO₂,²² MoS₂/Fe₃O₄ (ref. 23) and MoS₂/TiO₂ (ref. 24) and so on, indicating that improved the electrochemical performance due to it can maintain the stability of the structure during the charge/discharge process to buffer the volume change of MoS₂.²⁵

Cerium sulfide (Ce₂S₃) which exists in three crystal structure of α, β and γ phase has received considerable attention due to appealing special physical, thermal, mechanical, electronic, optical stability and excellent electrical conductivity.^{26–28} Therefore, huge efforts have been made to prepare various crystal structural Ce₂S₃ and their physical, chemical properties and application fields were studied. Ce₂S₃ is used as mainly nontoxic red pigment instead of heavy metal compounds at present. For example, Yu *et al.* prepared the γ-Ce₂S₃@SiO₂ by sulfurization method with corresponding CeO₂, which shows excellent thermal and acid stabilities.²⁹

To date, the preparation and application of Ce₂S₃/MoS₂ composite were barely explored. We prepared homogeneous Ce₂S₃/MoS₂ composite *via* an *in situ* sulfurization method and investigated their phase structure, morphology and electrochemical performance for the first time. The homogeneous Ce₂S₃/MoS₂ composite tested as anode materials for LIBs shown excellent electrochemical performance, including higher

^aKey Laboratory of Applied Chemistry and Nanotechnology at Universities of Jilin Province, Changchun University of Science and Technology, Changchun 130022, China. E-mail: wjx87@sina.com

^bState Key Laboratory of Rare Earth Resource Utilization, Changchun Institute of Applied Chemistry, CAS, Changchun, 130022, China



reversible capacity, exceptional cycle life, and good rate performance compared with Ce_2S_3 and MoS_2 .

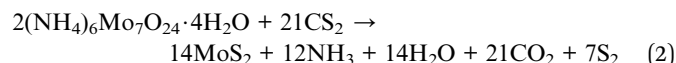
2. Experimental section

2.1. Materials

The Cerium carbonate ($\text{Ce}_2(\text{CO}_3)_3$, 99.95%, Shanghai AiBi Chemistry Preparation Co. Ltd. China), Carbon disulfide (CS_2 , boiling point: 46–47 °C, Tianjin Tiantai Fine Chemical Reagents Co. Ltd. China), Ammonium molybdate ($(\text{NH}_4)_6\text{Mo}_7\text{O}_{24} \cdot 4\text{H}_2\text{O}$, 99%, Shanghai AiBi Chemistry Preparation Co. Ltd. China) were used as the starting materials. Acetylene black, Polyvinylidene fluoride (PVDF) and *N*-methyl-2-pyrrolidone (NMP) were bought from Sinopharm Chemical Reagent Co. Ltd. Electrolyte (1 mol L^{-1} LiPF_6 in ethylene carbonate/dimethyl carbonate (1 : 1 v/v) solution) was purchased from Tianneng Group and counter electrode (pure lithium foil) was purchased from China Energy Lithium Co., Ltd. All chemicals were analytical grade and used as received without further purification.

2.2. Preparation of Ce_2S_3 , MoS_2 and homogeneous $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite

An *in situ* sulfurization method was used for preparing homogeneous $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite. The $\text{Ce}_2(\text{CO}_3)_3$ and $(\text{NH}_4)_6\text{Mo}_7\text{O}_{24} \cdot 4\text{H}_2\text{O}$ was mixed uniformly according to cationic ratio: Ce : Mo in 6 : 1, 5 : 1, 4 : 1 and 3 : 1. The mixture that was contained in graphite boat was introduced into high temperature furnace. After flushing with high-purity Ar gas at room temperature, the graphite boat was heated and held at 950 °C for 2 h. CS_2 was introduced into the quartz tube by passing Ar carrier gas through a bubbler containing liquid CS_2 . To minimize the carbon or sulfide from the thermal dissociation of CS_2 deposition on the sample, CS_2 was introduced only when the furnace was heated over 500 °C. After the desired reaction time at 950 °C, CS_2 was withdrawn before the furnace was cooled to 500 °C. The as-synthesized $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite with the cationic ratio of Ce : Mo = 6 : 1, 5 : 1, 4 : 1 and 3 : 1 were named as C6M1, C5M1, C4M1 and C3M1 for short. For the sulfurization method used for preparing Ce_2S_3 and MoS_2 , the conditions were similar to those for the fabrication of the $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite. The chemical reactions for the preparation of Ce_2S_3 and MoS_2 can be described by the chemical reaction (1) and (2):



2.3. Characterization methods

The crystal structure of as-prepared materials was studied by powder X-ray diffractometry (XRD, Dandong Tongda TD-3000) with the $\text{Cu K}\alpha$ (40 kV, 30 mA) radiation ($\lambda = 1.5406 \text{ \AA}$) over the range of 10–90° at a scanning speed of $0.01^\circ \text{ s}^{-1}$. The particle morphology and size of the as-prepared products were characterized by a scanning electron microscope (SEM, JMS-

7610F, JEOL, Japan). Chemical element composition and element spatial distribution analysis was performed with energy dispersive X-ray spectrum (EDX) spectrometer (OXFORDX-Max).

2.4. Electrochemical measurements

The anodes were manufactured using the above-obtained materials as the active materials, acetylene black as conductive additive, and PVDF as binder in the mass ratio of 80 : 10 : 10 dissolved in NMP. Then the mixed slurry was coated onto the Cu foil and dried in a vacuum at 120 °C for 24 h. Then the film was cut into discs with the loading mass of about 2 mg cm^{-2} . The electrochemical performances of the samples were tested by half cells assembled in an argon-filled glove box (H_2O , O_2 content < 1 ppm). Electrochemical measurements were carried out using 2032-type half cells with a pure lithium foil as the counter electrode, Celgard 2320 as the separator, and 1 mol L^{-1} LiPF_6 in ethylene carbonate/dimethyl carbonate (1 : 1 v/v) solution as the electrolyte. The charge–discharge performance was performed by battery testing system (BTS-5 V/10 mA, Neware Technology Co. Ltd. China) with a cutoffs potential of 0.01–3.0 V versus Li/Li^+ . Electrochemical impedance spectra (EIS) and cyclic voltammetry galvanostatic cycling (CV) measurements were evaluated on an electrochemical workstation (CHI-760D, Shanghai Chenhua Instrument Co. Ltd. China). For the CV measurements, the voltage was fixed between 0.01 V and 3.0 V and the scanning rate was fixed at 0.1 mV s^{-1} . For the EIS measurements, the amplitude of the alternating current signal to the cells was 10 mV and the frequency was between 100 kHz and 0.01 Hz.

3. Results and discussion

3.1. Structure and morphology characterization of Ce_2S_3 , MoS_2 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite

The XRD patterns of Ce_2S_3 , MoS_2 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite are shown in Fig. 1. XRD patterns of the MoS_2 are shown in Fig. 1a. The distinctive (002), (100), (103), (110) and (008) diffraction peaks indicate that MoS_2 has a hexagonal structure (JCPDS card no. 75-1539) with space group $P6_3/mmc$. The XRD patterns in Fig. 1b manifest the phase structure of Ce_2S_3 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite. All of the diffraction peaks in the XRD patterns clearly for Ce_2S_3 can be indexed to space group, $Pnma$ (JCPDS card no. 70-3159), indicative of perfect crystalline structure of

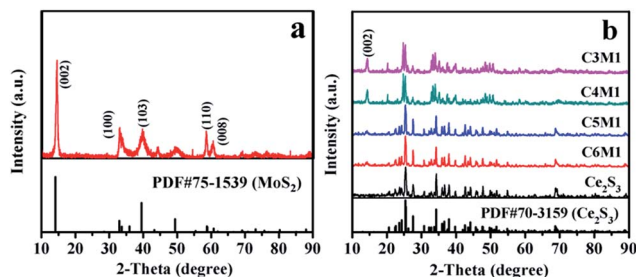


Fig. 1 (a) XRD patterns of MoS_2 . (b) XRD patterns of Ce_2S_3 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite.



orthorhombic Ce_2S_3 . For the structure of the $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite, despite the differences in their MoS_2 concentrations, all the peaks could be indexed to the orthorhombic structure Ce_2S_3 and hexagonal structure MoS_2 . The sharp peaks suggest all of products being highly crystallized. In addition, there is no shift of peaks that can be detected in all of XRD patterns of $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite, indicating that the compositing process has no impact on structure of Ce_2S_3 . The results mentioned above indicate that MoS_2 is successfully composited in the Ce_2S_3 .

The SEM images in Fig. 2a–f show the morphology of Ce_2S_3 , MoS_2 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite, which can be observed that obvious changes of morphology of $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite have taken place compared to Ce_2S_3 and MoS_2 , presenting spherical secondary particles of 0.5–1 μm in diameter. Among them, C4M1 have the largest particle size, which aggregate each other to form spherical secondary particles of 1–1.5 μm in diameter with flower-like structure on the surface of particle. To further confirm the element composition and element spatial distribution of $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite, the EDX spectrum and spatial elemental mappings of C4M1 are demonstrated in Fig. 3, which proves that the $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite cover the elements $\text{S K}\alpha 1$, $\text{Mo L}\alpha 1$, and $\text{Ce L}\alpha 1$ and the homogeneous distribution of all these elements and the Pt peaks in the spectrum come from platinum conductive film plated on the surface of the sample for SEM observation. All the results mentioned above indicate that MoS_2 is successfully composited in the Ce_2S_3 .

3.2. Electrochemical performance of Ce_2S_3 , MoS_2 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite

The voltage profiles of Ce_2S_3 , MoS_2 and $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite electrodes during the first cycle at a current density of 100 mA g^{-1} with voltage cutoffs of 0.01 V and 3.0 V *versus* Li/Li^+ are shown in Fig. 4a. During initial lithiation process, two plateaus located at 1.2 V and 0.7 V are observed in voltage profiles of MoS_2 , corresponding to the discharge capacity of 887.5 mA h g^{-1} and 88.4% coulombic efficiency. The first plateau

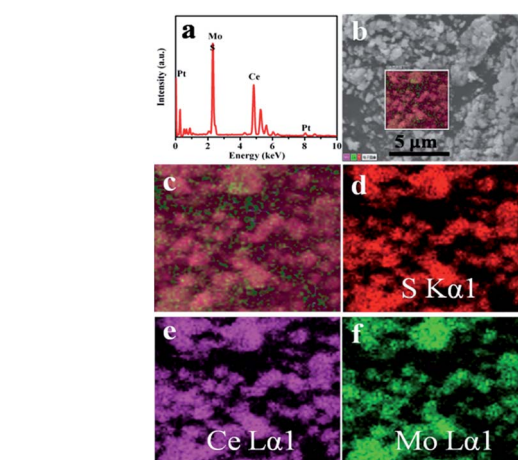


Fig. 3 The chemical element composition and elemental mappings of C4M1 composite. (a) EDX spectrum, (b and c) SEM images and (d–f) Elemental mappings of C4M1.

corresponds to the intercalation of Li-ions to MoS_2 electrodes materials, and the second plateau is ascribed to the phase conversion reaction of MoS_2 .^{18,19} Remarkably, two plateaus located at 1.2 V and 0.7 V are also observed in voltage profiles of $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite during initial lithiation process, corresponding to the discharge capacities of 139.8, 173.9, 225.5 and 251.5 mA h g^{-1} and 86.8%, 82.5%, 99.1% and 84.2% coulombic efficiency, which can be ascribed to the intercalation of Li-ions to $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite electrodes and phase conversion reaction possibly. Overall, initial discharge capacity of composite shows upward trend with increasing content of MoS_2 in composite, which can attribute to the reason that is MoS_2 exhibits high Li storage capacity (669 mA h g^{-1})^{6–8} that is much higher than that of Ce_2S_3 . So, MoS_2 can provide a high charge/discharge capacity for composite electrode materials. For voltage profiles of Ce_2S_3 electrode, a sloping curve is observed and no clearly potential plateau can be detected in initial

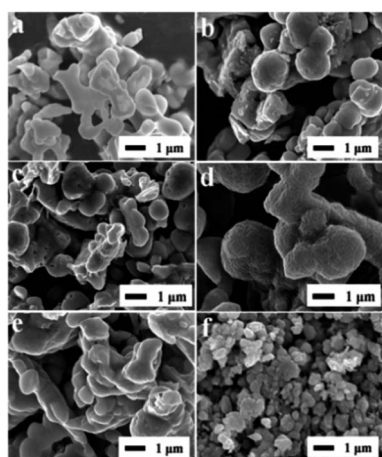


Fig. 2 SEM images of (a) Ce_2S_3 , (b) C6M1, (c) C5M1, (d) C4M1, (e) C3M1 and (f) MoS_2 , respectively.

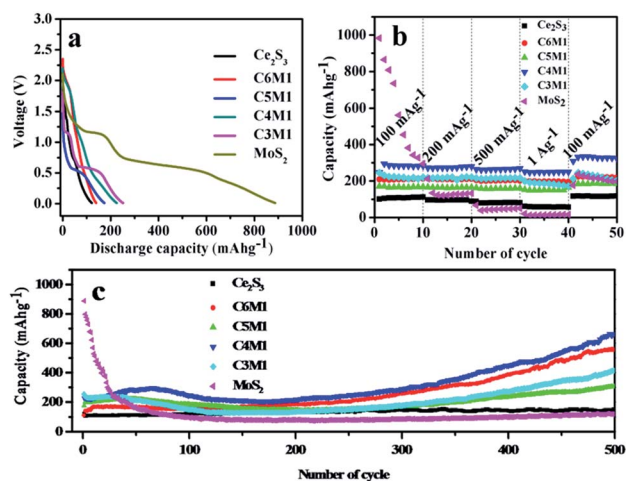


Fig. 4 The charge and discharge profiles of as-prepared samples. (a) First discharge voltage curves, (b) rate performances curves, (c) cycling performance curves of MoS_2 , Ce_2S_3 and the $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite.



lithiation process. The discharge capacity is 121.5 mA h g⁻¹ at a current density of 100 mA g⁻¹, corresponding to a 76% coulombic efficiency.

In addition, Ce₂S₃/MoS₂ composite electrodes exhibit much better rate capability compared to Ce₂S₃ and MoS₂ electrodes operated at various current density between 100 mA g⁻¹ and 1000 mA g⁻¹ (Fig. 4b). It can be found that the discharge capacity remains stable and decreases regularly with the increased current density. After each 10 cycles at high current density of 1000 mA g⁻¹, the average reversible capacities are about 81, 213, 187, 286, 202 and 23 mA h g⁻¹ for Ce₂S₃, C6M1, C5M1, C4M1, C3M1 and MoS₂ electrodes, implying that the rate cycling stability of Ce₂S₃/MoS₂ composite electrodes is excellent. Among the composite, C4M1 shows perfect capacity retention and the highest discharge capacity at high current density of 1000 mA g⁻¹. Remarkably, when the current density is got back to 100 mA g⁻¹, the discharge capacity of Ce₂S₃/MoS₂ composite can be recovered (even a little higher than the original capacity at 100 mA g⁻¹), which shows the compositing between MoS₂ and Ce₂S₃ enhance the structure stability of Ce₂S₃/MoS₂ composite at various current density.

The cycling performance is an important factor to determine the practical applications of an electrode material in practical battery. The typical cycle performance of Ce₂S₃, MoS₂ and Ce₂S₃/MoS₂ composite electrodes cycling at a current density of 100 mA g⁻¹ in the voltage range of 0.01–3.0 V are shown in Fig. 4c. After being charged/discharged at a current density of 100 mA g⁻¹ for 500 cycles, the MoS₂ electrode shows only capacity retention of 11.22% (*vs.* to the first discharge capacity). The reason why MoS₂ shows high degradation rate is that MoS₂ with Li reaction at a low voltage range suffers from cracking and crumbling due to their vast volume expansion/contraction during repeated charge/discharge process, which leads to a significant capacity fading by loss of inter-particle contact in the electrode. In addition, Li₂S that is the product of conversion reaction can react with the electrolyte to form a thick gel-like polymeric layer, which restrain successive lithiation and delithiation reaction during cycling resulting in a poor cycle stability and a low rate capability.²⁵ Interestingly, the Ce₂S₃ electrode did not go through capacity fading at current density of 100 mA g⁻¹. Instead, capacity at the 500th cycle is 24.4% higher than the capacity at the 1st cycle, which shows that Ce₂S₃ exhibits excellent structure stability during charge/discharge process. Remarkably, for the Ce₂S₃/MoS₂ composite electrodes, capacity at the 500th cycle is 459.2, 306.3, 661.7 and 414.6 mA h g⁻¹ at current density of 100 mA g⁻¹, respectively, which are higher than the capacity at the 1st cycle. Further studies need to be conducted to analyze the reasons for this phenomenon. The results show that the cycle performance of Ce₂S₃/MoS₂ composite, especially, C4M1 exhibits the most excellent cycling performance and the highest discharge capacity compared with Ce₂S₃ and MoS₂ electrodes. One of reason is that the compositing between MoS₂ and Ce₂S₃ can enhance the structure stability during the charge/discharge process. On the other hand, exists of Ce₂S₃ can enhance the electrical conductivity of electrodes materials, which can be detected in

electrochemical impedance spectra of Ce₂S₃, MoS₂ and Ce₂S₃/MoS₂ composite in Fig. 5a.

To analyze the lithium diffusion constant, EIS measurements were performed. All Nyquist plots are shown in Fig. 5a. Electrochemical impedance spectra of all of the samples show a compressed semicircle in the high-to-medium frequency region and a straight line in the low frequency region.³⁰ The semicircle corresponds to the complex charge transfer the solid electrolyte interface (SEI) formed on the electrodes surface. The inclined line is attributed to the Warburg impedance and could be responsible for the lithium ion diffusion in the Ce₂S₃, MoS₂ and Ce₂S₃/MoS₂ composite, standing for the resistance between the electrolyte and the active material. The diameter of the semicircle in high frequency range is smaller for Ce₂S₃/MoS₂ composite and the Warburg component of the spectra of this system has a bigger slope compared with Ce₂S₃ and MoS₂. Apparently, the charge transfer resistance of C4M1 (58.28 Ω) is much lower than that of Ce₂S₃ (101.54 Ω), C6M1 (74.37 Ω), C5M1 (105.46 Ω), C3M1 (78.61 Ω) and MoS₂ (150.26 Ω), which could indicate the enhanced charge transfer and lithium ion conduction in C4M1 particles, which agrees with the charge-discharge curves, and could be one of the main reason of the good cycling performance and rate performance of C4M1.

The CV curves of the Ce₂S₃, MoS₂ and C4M1 at a scanning rate of 0.1 mV s⁻¹ are shown in Fig. 5b–d. For CV curve of MoS₂, in the first cathodic sweep, two peaks at 1.2 and 0.7 V were observed. The first peak at 1.2 V was related to the lithium insertion reaction that led to the formation of Li_xMoS₂. Also, the second peak at 0.7 V is attributable to a conversion reaction of MoS₂,^{18,19,31,32} which can be described as MoS₂ + 4Li → Mo + 2Li₂S. There is an oxidation peak at 2.2 V in the first anodic sweep, corresponding to the oxidation of Mo to form MoS₂. The lithium storage mechanism of MoS₂ electrode can be described by the electrochemical conversion reaction²⁵ (3)–(5):

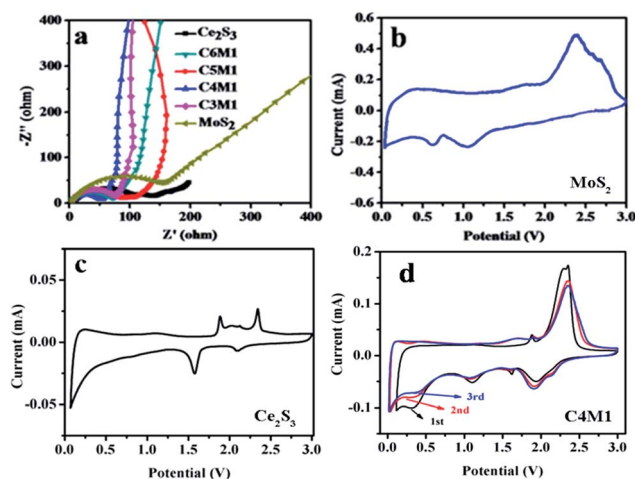
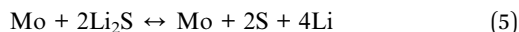
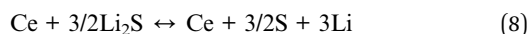
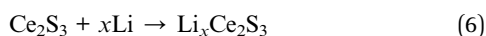


Fig. 5 (a) Electrochemical impedance spectra (EIS) of Ce₂S₃, MoS₂ and Ce₂S₃/MoS₂ composite. (b–d) CV curves of MoS₂, Ce₂S₃ and the C4M1.





For CV curve of the Ce_2S_3 , in the first cathodic scan, two peaks at 2.1 and 1.72 V are observed, maybe corresponding to the formation of $\text{Li}_x\text{Ce}_2\text{S}_3$ phase and the reduction process of $\text{Ce}^{4+} \rightarrow \text{Ce}^{3+}$ which fits with standard electrode potential (1.72 V), respectively. During the first anodic sweep, the electrode exhibits two peaks at 1.8 and 2.336 V correspond to de-lithiation back to orthorhombic Ce_2S_3 and oxidation process of $\text{Ce} \rightarrow \text{Ce}^{3+}$ which corresponds to standard electrode potential (2.336 V), respectively. The formation of Ce during reduction process of electrode materials can improve the conductivity of the electrode. The lithium storage mechanism of Ce_2S_3 electrode may be described by the electrochemical conversion reaction (6)–(8):



For CV curves of the C4M1, it is clear that the CV curve of the first cycle is the same as those of subsequent cycles, especially for the charge branch. In the first cathodic sweep, four peaks at 0.7, 1.2, 1.72 and 2.1 V were observed. The peaks at 1.2 and 0.7 V correspond to reduction peaks of MoS_2 in composite and peaks at 1.72 and 2.1 V correspond to reduction peaks of Ce_2S_3 in composite, respectively. In the first anodic sweep, three peaks at 1.8, 2.2 and 2.336 V were observed. The peak at 2.2 V corresponds to oxidation peak of MoS_2 in composite and peaks at 1.8 and 2.336 V correspond to oxidation peaks of Ce_2S_3 in composite, respectively. In the second and third cycle, both the intensity and position of reduction and oxidation peaks is decreasing and shifting, respectively. It can be ascribed to the polarization of the electrode in the first cycle. It is noteworthy that after the first cycle, the CV curves almost overlapped, suggesting a good reversibility of C4M1.

4. Conclusions

An *in situ* sulfurization method has been successfully applied to fabricate homogeneous $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite and their phase structure, morphology, element composition and distribution and electrochemical properties are researched systematically by XRD, SEM, EDX and electrochemical measurements for the first time. Results show that $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite present spherical secondary particles of 0.5–1 μm in diameter. The cycling performance and rate property of $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite are better than those of Ce_2S_3 and MoS_2 as anode materials for lithium ion batteries. The electrochemical performance of MoS_2 and Ce_2S_3 has been improved after compositing. It is found that C4M1 has the best electrochemical properties, which has an initial discharge capacity of 225.5 mA h g^{-1} , coulombic efficiency of 99.1% and a reversible capacity as high as 661.7 mA h g^{-1} , coulombic efficiency of 99.7% after 500 cycles at a current density of 100 mA g^{-1} and the highest discharge capacity of

285.6 mA h g^{-1} at a high current density of 1000 mA g^{-1} . The enhanced cycling stability and rate performance of C4M1 could be attributed to the structure stabilization and the enhanced electrical conductivity of C4M1. The strategy in this study not only represents a promising avenue for developing high-performance $\text{Ce}_2\text{S}_3/\text{MoS}_2$ composite, but also can be easily extended to the fabrication of other anode and cathode materials for next-generation LIBs.

Acknowledgements

This research has been supported by the Natural Science Foundation of Jilin Province (No. 20170101128JC), Ph.D. Programs Foundation of the Ministry of Education of China (20102216110002, 20112216120003), the Science and Technology Planning Project of Changchun City (No. 2013064).

References

- 1 A. Vu, Y. Q. Qian and A. Stein, *Adv. Energy Mater.*, 2012, **2**, 1056–1085.
- 2 J. B. Goodenough and K. Youngsik, *J. Mater. Chem.*, 2009, **22**, 587–603.
- 3 V. Etacheri, R. Marom, R. Elazari, G. Salitra and D. Aurbach, *Energy Environ. Sci.*, 2011, **4**, 3243–3262.
- 4 B. Dunn, H. Kamath and J. M. Tarascon, *Science*, 2011, **334**, 928–935.
- 5 S. M. Liu, J. X. Wang, J. W. Wang, F. F. Zhang, F. Liang and L. M. Wang, *CrystEngComm*, 2014, **16**, 814–819.
- 6 H. H. Wang, H. Kim and J. Cho, *Nano Lett.*, 2011, **11**, 4826–4830.
- 7 J. Xiao, D. Choi, L. Cosimbescu, P. Koech, J. Liu and J. P. Lemmon, *Chem. Mater.*, 2010, **22**, 4522–4524.
- 8 C. N. R. Rao, K. Gopalakrishnan and U. Maitra, *ACS Appl. Mater. Interfaces*, 2015, **7**, 7809–7832.
- 9 S. Ding, D. Zhang, J. S. Chen and X. W. Lou, *Nanoscale*, 2012, **4**, 95–98.
- 10 Q. C. Pan, Y. G. Huang, H. Q. Wang, G. H. Yang, L. C. Wang, J. Chen and Q. Y. Li, *Electrochim. Acta*, 2016, **197**, 50–57.
- 11 C. F. Zhang, H. B. Wu, Z. P. Guo and X. W. Lou, *Electrochem. Commun.*, 2012, **20**, 7–10.
- 12 H. Li, L. Ma, W. X. Chen and J. M. Wang, *Mater. Lett.*, 2009, **63**, 1363–1365.
- 13 K. Chang, W. Chen, L. Ma, H. Li, H. Li, F. Huang, Z. Xu, Q. Zhang and J. Y. Lee, *J. Mater. Chem.*, 2011, **21**, 6251–6257.
- 14 S. Ding, J. S. Chen and X. W. Lou, *Chem.–Eur. J.*, 2011, **17**, 13142–13145.
- 15 S. K. Park, S. H. Yu, S. Woo, B. Quan, D. C. Lee, M. K. Kim, Y. E. Sung and Y. Piao, *Dalton Trans.*, 2013, **42**, 2399–2405.
- 16 S. Wang, X. Jiang, H. Zheng, H. Wu, S. J. Kim and C. Feng, *Nanosci. Nanotechnol. Lett.*, 2012, **4**, 378–383.
- 17 Y. G. Guo, X. Zhou and L. j. Wan, *Chem. Commun.*, 2013, **49**, 1838–1840.
- 18 K. Chang and W. Chen, *ACS Nano*, 2011, **5**, 4720–4728.
- 19 K. Chang and W. Chen, *Chem. Commun.*, 2011, **47**, 4252–4254.



- 20 C. Wang, W. Wan, Y. Huang, J. Chen, H. H. Zhou and X. X. Zhang, *Nanoscale*, 2014, **6**, 5351–5358.
- 21 K. Chang, W. Chen, L. Ma, H. Li, H. Li, F. Huang, Z. Xu, Q. Zhang and J. Y. Lee, *J. Mater. Chem.*, 2011, **21**, 6251–6257.
- 22 L. Ma, X. Zhou, L. Xu, X. Xu and L. Zhang, *Nano*, 2016, **11**, 1650023–1650028.
- 23 B. Song, X. Tang, L. Lu and J. Xue, *Small*, 2014, **10**, 1536–1543.
- 24 W. Zhuang, L. C. Li, J. H. Zhu, R. An, L. H. Lu, X. H. Lu, X. B. Wu and H. J. Ying, *ChemElectroChem*, 2015, **2**, 374–381.
- 25 X. D. Xu, W. Liu, Y. Kim and J. Cho, *Nano Today*, 2014, **9**, 604–630.
- 26 T. Takeshita, K. A. Gschneidner Jr and B. J. Beaudry, *J. Appl. Phys.*, 1985, **57**, 4633–4637.
- 27 C. M. Forster and W. B. White, *J. Am. Ceram. Soc.*, 1997, **80**, 273–276.
- 28 C. M. Forster and W. B. White, *Mater. Res. Bull.*, 2006, **41**, 448–454.
- 29 S. Yu, D. Wang, Y. Liu, Z. Li, X. Zhang, Y. Wang, X. Wang and H. Su, *RSC Adv.*, 2014, **4**, 23653–23657.
- 30 S. S. Zhang, K. Xu and T. R. Jow, *Electrochim. Acta*, 2004, **49**, 1057–1061.
- 31 J. Xiao, X. Wang, X. Q. Yang, S. Xun, G. Liu, P. K. Koech and J. P. Lemmon, *Adv. Funct. Mater.*, 2011, **21**, 2840–2846.
- 32 S. K. Park, S. H. Yu, S. Woo, J. Ha, J. Shin, Y. E. Sung and Y. Piao, *CrystEngComm*, 2012, **14**, 8323–8325.

